

P-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

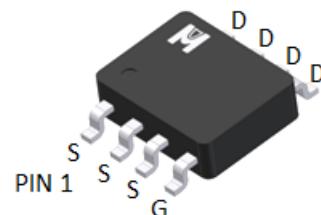
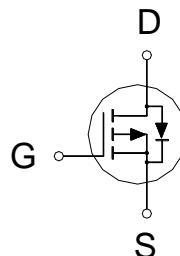
$BV_{DSS}$	-20V
$R_{DS(on)}$ (MAX.)	9.5mΩ
$I_D$	-13A

P Channel MOSFET

UIS,  $R_g$  100% Tested

Pb-Free Lead Plating & Halogen Free

**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$  Unless Otherwise Noted)**



PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNIT
Gate-Source Voltage		$V_{GS}$	±8	V
Continuous Drain Current	$T_A = 25^\circ C$	$I_D$	-13	A
	$T_A = 100^\circ C$		-8	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	-53	
Avalanche Current		$I_{AS}$	-38	
Avalanche Energy	$L = 0.1mH$	$E_{AS}$	72	mJ
Repetitive Avalanche Energy <sup>2</sup>	$L = 0.05mH$	$E_{AR}$	36	
Power Dissipation	$T_A = 25^\circ C$	$P_D$	2.5	W
	$T_A = 70^\circ C$		1.0	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Case	$R_{\theta JC}$		25	°C / W
Junction-to-Ambient <sup>3</sup>	$R_{\theta JA}$		50	

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle ≤ 1%

<sup>3</sup>50°C / W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Noted)

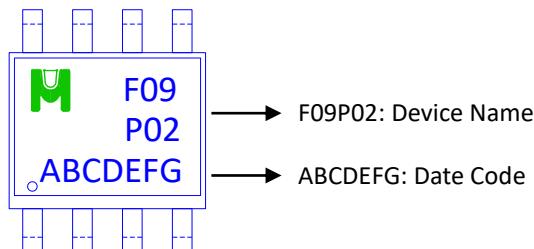
PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = -250\mu\text{A}$	-20			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	-0.4	-0.75	-1.2	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 8V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -16V, V_{GS} = 0V$			-1	$\mu\text{A}$
		$V_{DS} = -12V, V_{GS} = 0V, T_J = 125^\circ\text{C}$			-10	
On-State Drain Current <sup>1</sup>	$I_D(\text{ON})$	$V_{DS} = -5V, V_{GS} = -4.5V$	-13			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(\text{ON})}$	$V_{GS} = -4.5V, I_D = -15\text{A}$		7.8	9.5	$\text{m}\Omega$
		$V_{GS} = -2.5V, I_D = -8\text{A}$		10.3	12.5	
		$V_{GS} = -1.8V, I_D = -5\text{A}$		14.5	18	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = -5V, I_D = -15\text{A}$		32		S
DYNAMIC						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = -10V, f = 1\text{MHz}$		4655		$\text{pF}$
Output Capacitance	$C_{oss}$			503		
Reverse Transfer Capacitance	$C_{rss}$			470		
Gate Resistance	$R_g$	$V_{GS} = 15\text{mV}, V_{DS} = 0V, f = 1\text{MHz}$		3.0		$\Omega$
Total Gate Charge <sup>1,2</sup>	$Q_g(V_{GS}=-4.5V)$	$V_{DS} = -10V, V_{GS} = -4.5V, I_D = -15\text{A}$		45		$\text{nC}$
	$Q_g(V_{GS}=-2.5V)$			26		
Gate-Source Charge <sup>1,2</sup>	$Q_{gs}$			5.5		
Gate-Drain Charge <sup>1,2</sup>	$Q_{gd}$			10.5		
Turn-On Delay Time <sup>1,2</sup>	$t_{d(on)}$	$V_{DS} = -10V, I_D = -1\text{A}, V_{GS} = -4.5V, R_{GS} = 6\Omega$		25		$\text{nS}$
Rise Time <sup>1,2</sup>	$t_r$			55		
Turn-Off Delay Time <sup>1,2</sup>	$t_{d(off)}$			150		
Fall Time <sup>1,2</sup>	$t_f$			65		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ )						
Continuous Current	$I_S$				-13	A
Pulsed Current <sup>3</sup>	$I_{SM}$				-53	
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = -15\text{A}, V_{GS} = 0V$			-1.2	V

<sup>1</sup>Pulse test : Pulse Width  $\leq 300\ \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .<sup>2</sup>Independent of operating temperature.<sup>3</sup>Pulse width limited by maximum junction temperature.

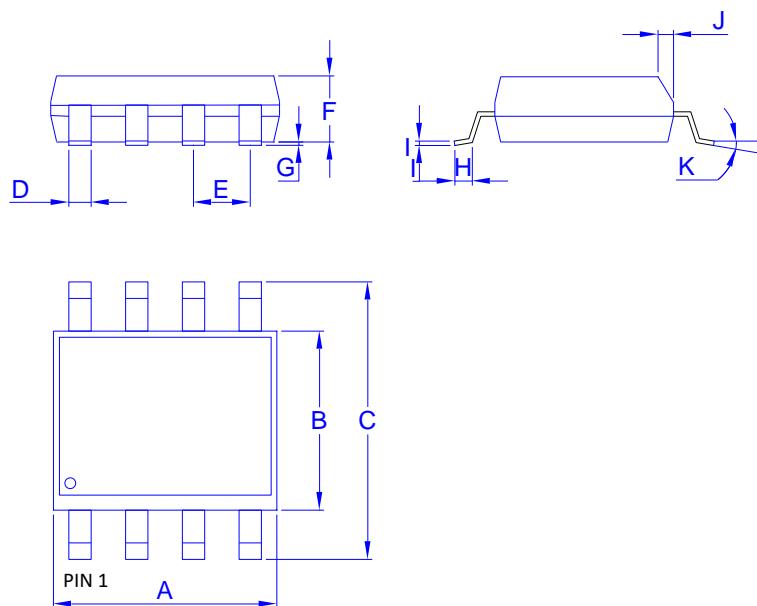
EMC will review datasheet by quarter, and update new version.

Ordering & Marking Information:

Device Name: EMF09P02G for SOP-8



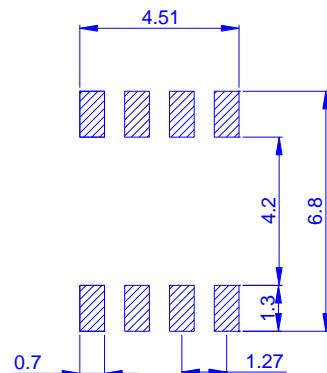
Outline Drawing



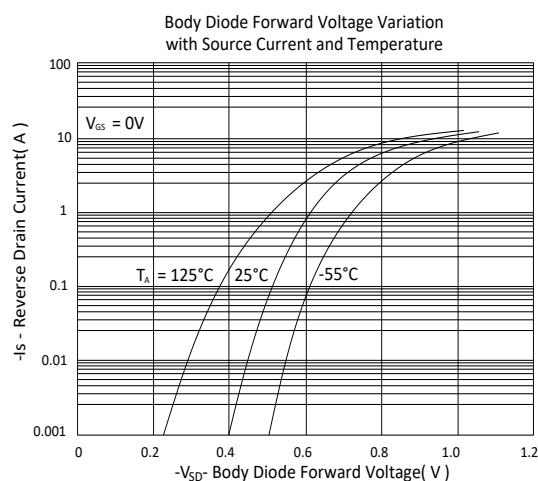
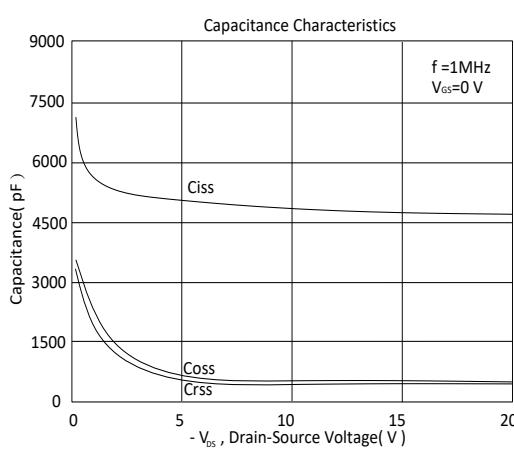
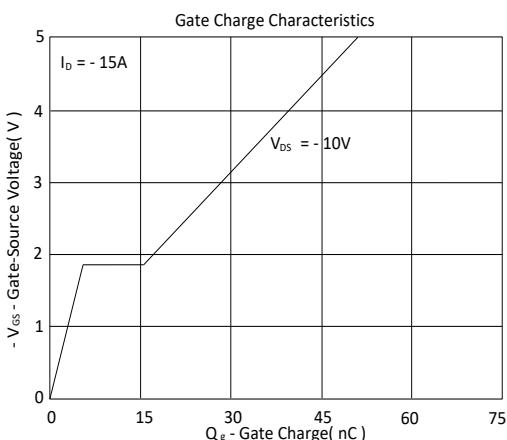
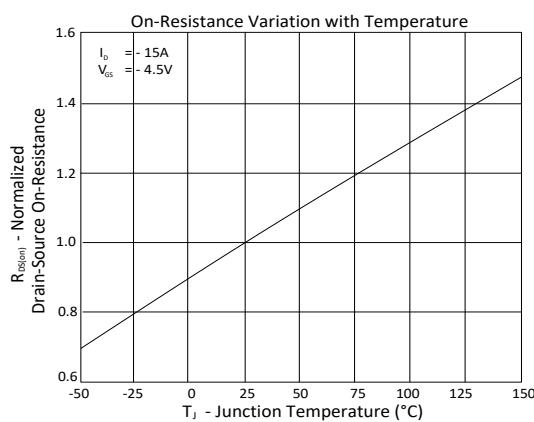
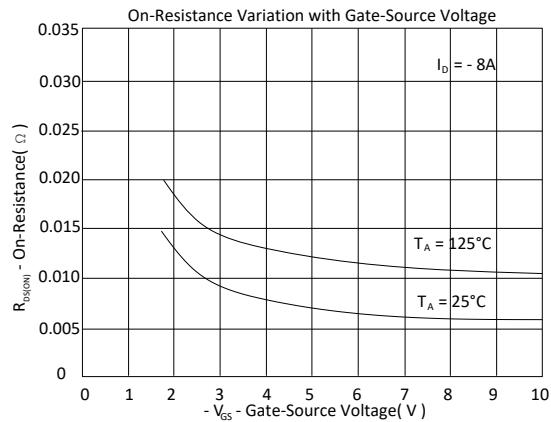
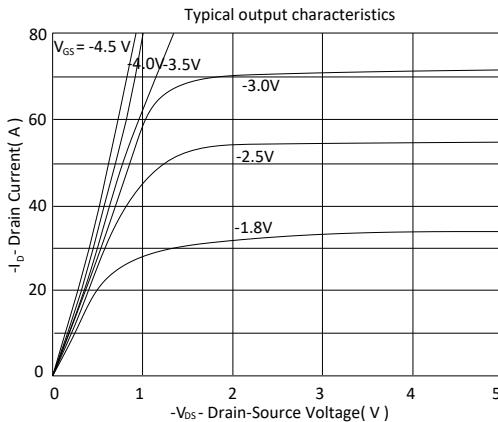
Dimension in mm

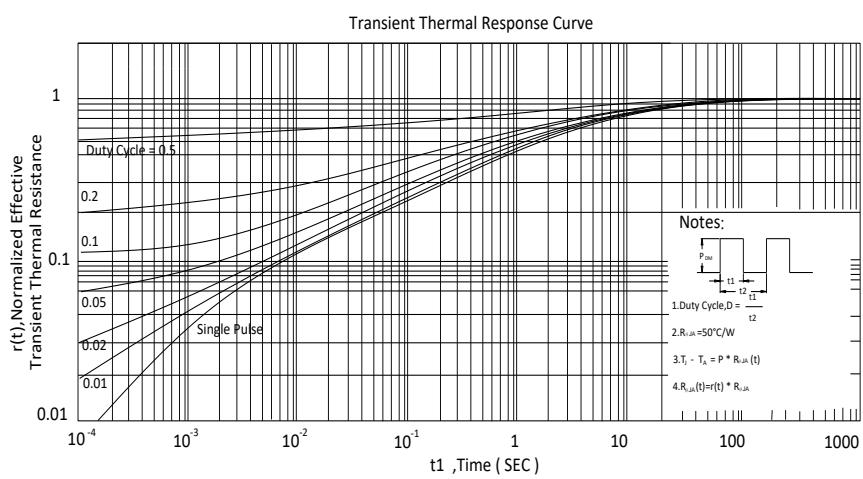
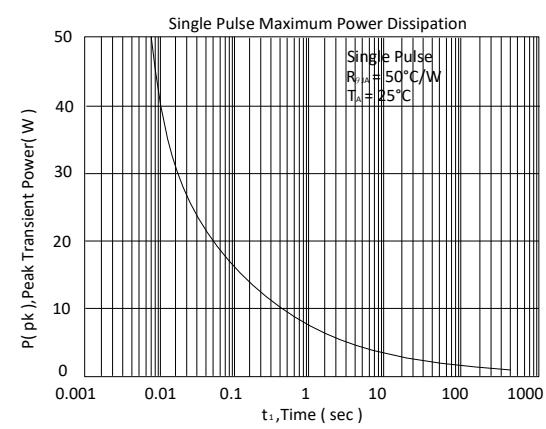
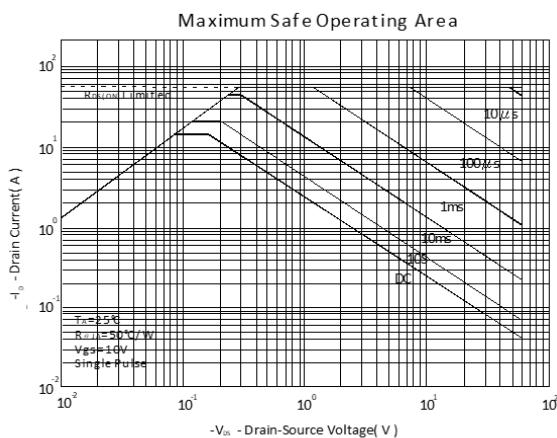
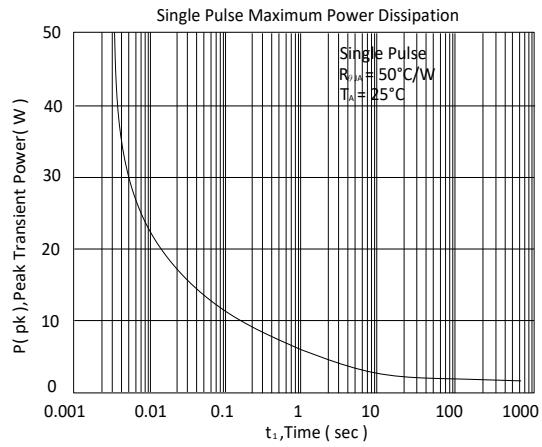
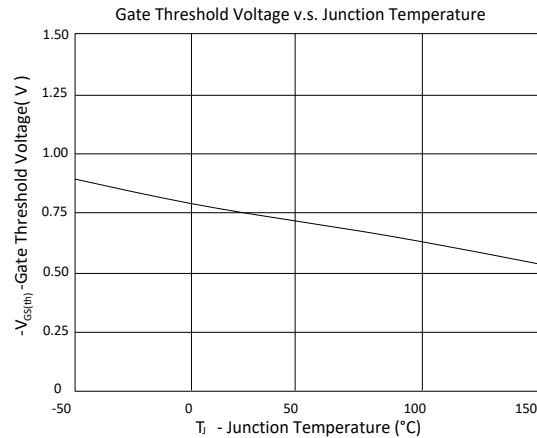
Dimension	A	B	C	D	E	F	G	H	I	J	K
Min.	4.70	3.80	5.80	0.31		1.35	0.01	0.40	0.10	0.25	0°
Typ.	4.90	3.90	6.00	0.41	1.27	1.55	0.18	0.60	0.20	0.30	
Max.	5.10	4.00	6.20	0.51		1.75	0.25	1.27	0.25	0.50	8°

Footprint



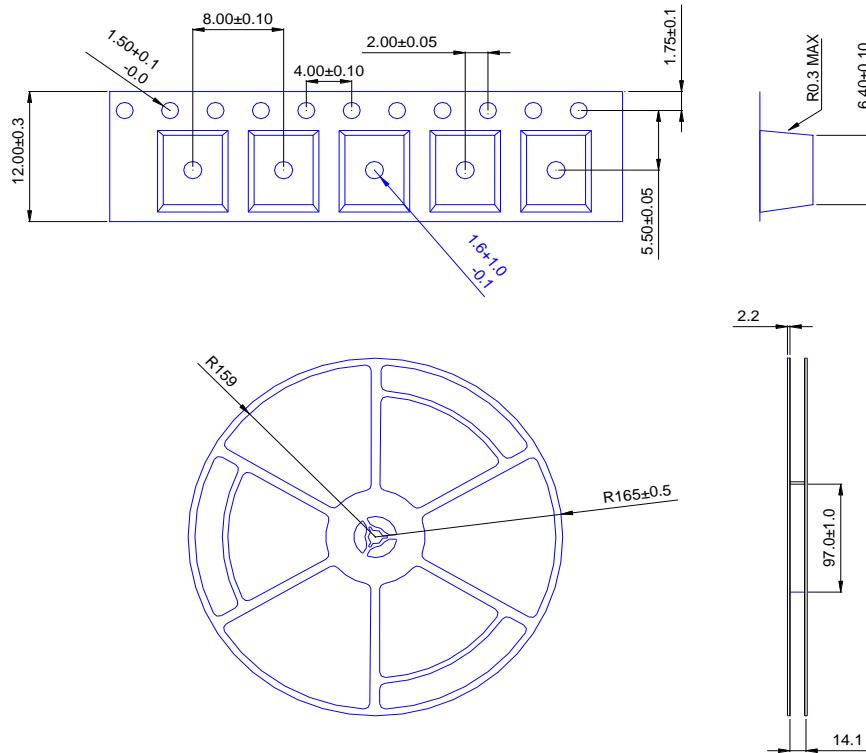
### TYPICAL CHARACTERISTICS







◆Tape&Reel Information:2500pcs/Reel



產品別	SOP-8
Reel 尺寸	13"
編帶方式	FEED DIRECTION 
前空格	25
後空格	50
裝箱數	
滿捲數量	2.5K
捲/內盒比	1 : 1
內盒滿箱數	2.5K
內/外箱比	10 : 1
外箱滿箱數	25K